2SB0945 (2SB945)

Silicon PNP epitaxial planar type

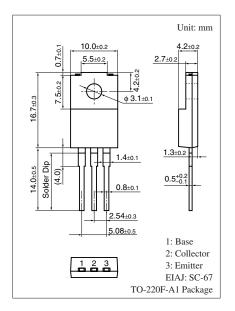
For power switching Complementary to 2SD1270

■ Features

- Low collector-emitter saturation voltage V_{CE(sat)}
- \bullet Satisfactory linearity of forward current transfer ratio h_{FE}
- Large collector current I_C
- Full-pack package which can be installed to the heat sink with one screw.

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	-130	V
Collector-emitter voltage (Base open)	V _{CEO}	-80	V
Emitter-base voltage (Collector open)	V _{EBO}	-7	V
Collector current	I_{C}	-5	A
Peak collector current	I_{CP}	-10	A
Collector power	P _C	40	W
dissipation $T_a = 25^{\circ}C$		2	
Junction temperature	T_{j}	150	°C
Storage temperature	T_{stg}	-55 to +150	°C



■ Electrical Characteristics $T_C = 25$ ° $C \pm 3$ °C

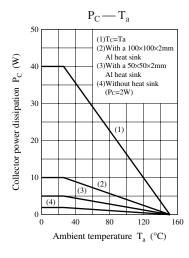
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = -10 \text{ mA}, I_B = 0$	-80			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -100 \text{ V}, I_E = 0$			-10	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = -5 \text{ V}, I_C = 0$			-50	μΑ
Forward current transfer ratio	h _{FE1}	$V_{CE} = -2 \text{ V}, I_{C} = -0.1 \text{ A}$	45			_
	h _{FE2} *	$V_{CE} = -2 \text{ V}, I_{C} = -2 \text{ A}$	60		260	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = -4 \text{ A}, I_B = -0.2 \text{ A}$			- 0.5	V
Base-emitter saturation voltage	V _{BE(sat)}	$I_C = -4 \text{ A}, I_B = -0.2 \text{ A}$			-1.5	V
Transition frequency	f_T	$V_{CE} = -10 \text{ V}, I_{C} = -0.5 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time	t _{on}	$I_C = -2 A$, $I_{B1} = -0.2 A$, $I_{B2} = 0.2 A$		0.13		μs
Storage time	t _{stg}	$V_{CC} = -50 \text{ V}$		0.50		μs
Fall time	$t_{\rm f}$			0.13		μs

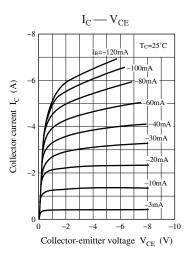
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

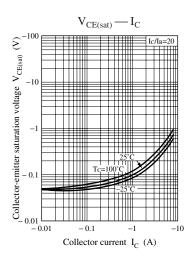
2. *: Rank classification

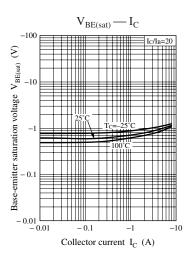
Rank	R	Q	Р
h _{FE2}	60 to 120	90 to 180	130 to 260

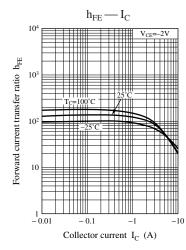
Note) The part number in the parenthesis shows conventional part number.

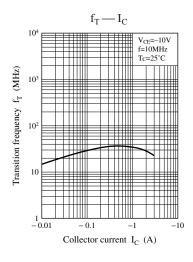


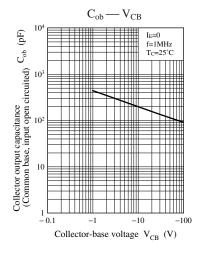


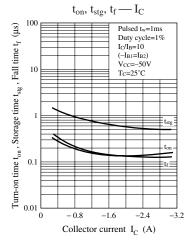


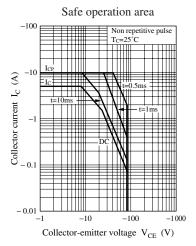


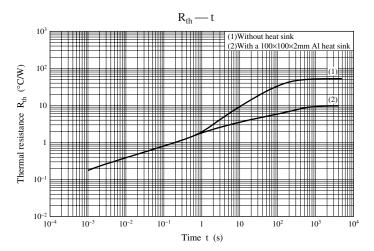












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